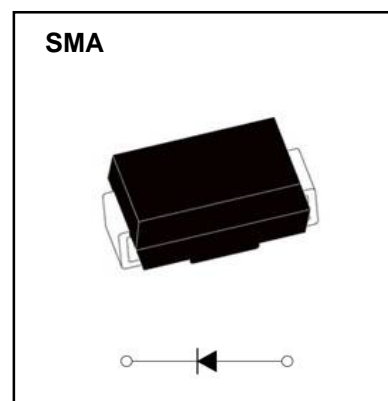


SMA Plastic-Encapsulate Diodes

Features

- $I_{F(AV)}$ 2A
- V_{RRM} 20V-200V
- High surge current capability
- Polarity: Color band denotes cathode



Applications

- Rectifier

Marking

- SS2X
- X : From 2 To 20

Limiting Values(Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	SS2														
				2	3	4	5	6	8	10	15	20						
Repetitive Peak Reverse Voltage	V_{RRM}	V		20	30	40	50	60	80	100	150	200						
Maximum RMS Voltage	V_{RMS}	V		14	21	28	35	42	56	70	105	140						
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load	2.0														
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	50														
Junction Temperature	T_J	$^\circ\text{C}$		-55~+125					-55~+150									
Storage Temperature	T_{STG}	$^\circ\text{C}$		-55 ~ +150														

Electrical Characteristics (T =25°C Unless otherwise specified)

Item	Symbol	Unit	Test Condition	SS2														
				2	3	4	5	6	8	10	15	20						
Peak Forward Voltage	V_F	V	$I_F=2.0A$	0.55		0.70		0.85		0.95								
Peak Reverse Current	I_{RRM1}	mA	$V_{RM}=V_{RRM}$	$T_a=25^\circ\text{C}$		0.5		0.1										
	I_{RRM2}			$T_a=100^\circ\text{C}$		10		5.0										
Thermal Resistance	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	Between junction and ambient	88														
	$R_{\theta J-L}$		Between junction and terminal	28														
Junction Capacitance (Typical)	C_j	pF	Measured at 1MHZ and Applied Reverse Voltage of 4.0 V.D.C	114		92		53		40								

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on FR4 PCB double sided copper mini pad



SS22 THRU SS220

Schottky Rectifier Diodes

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

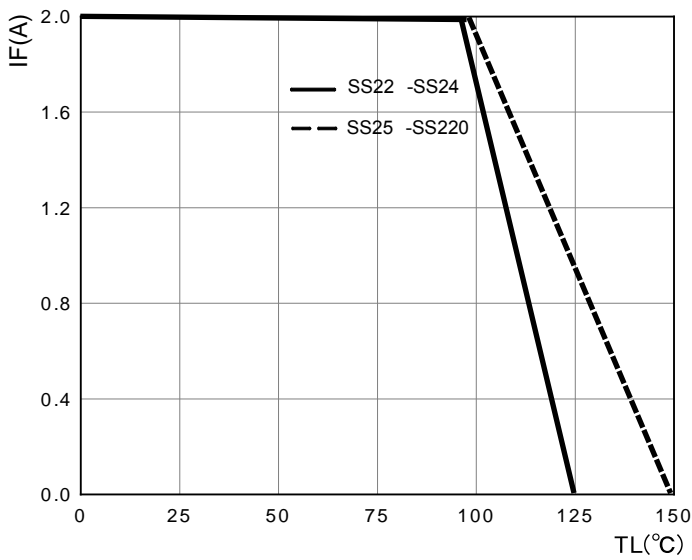
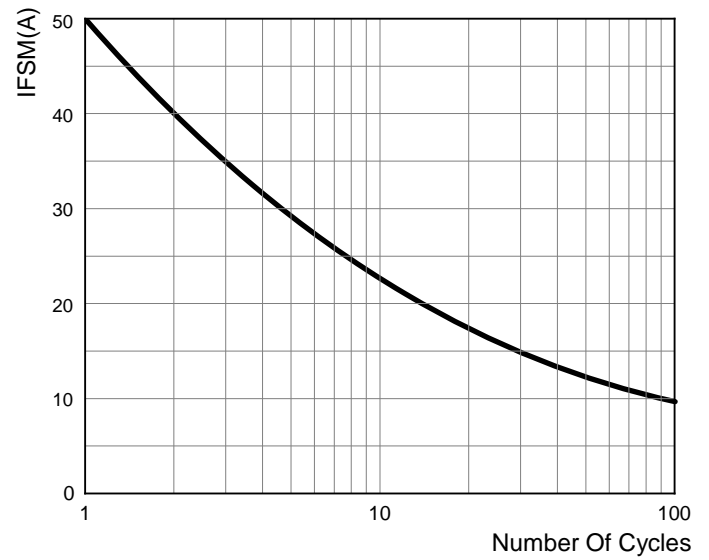
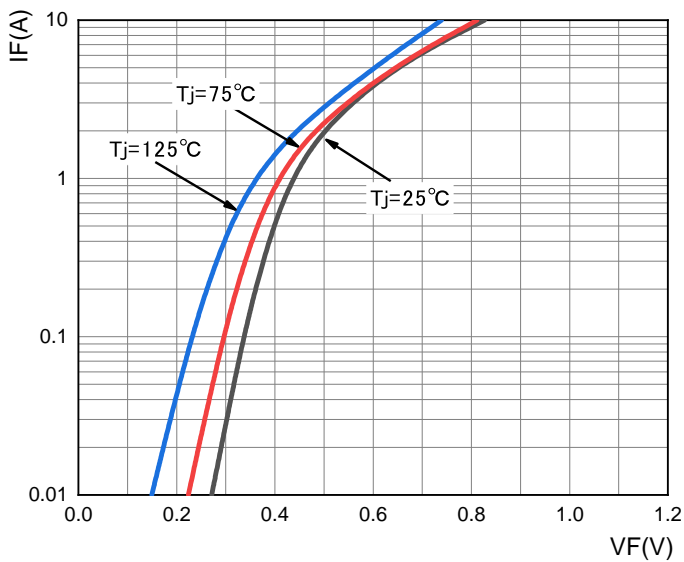


FIG.2: MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT



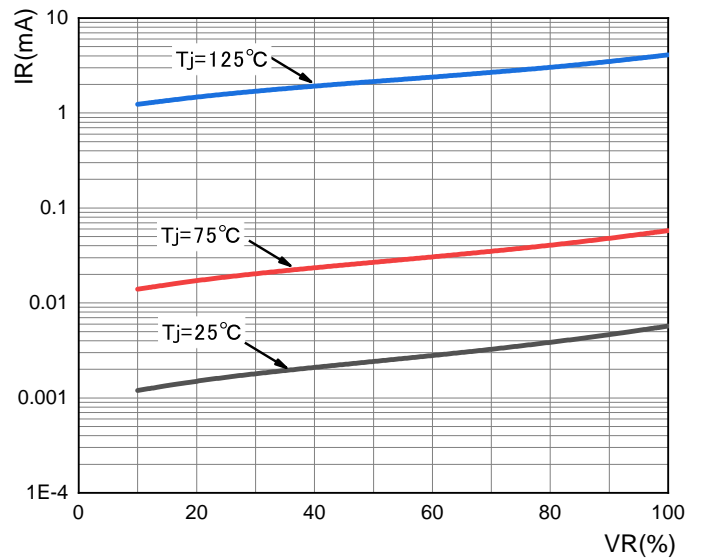
SS22-SS24

FIG.3: TYPICAL FORWARD CHARACTERISTICS



SS22-SS24

FIG.4: TYPICAL REVERSE CHARACTERISTICS





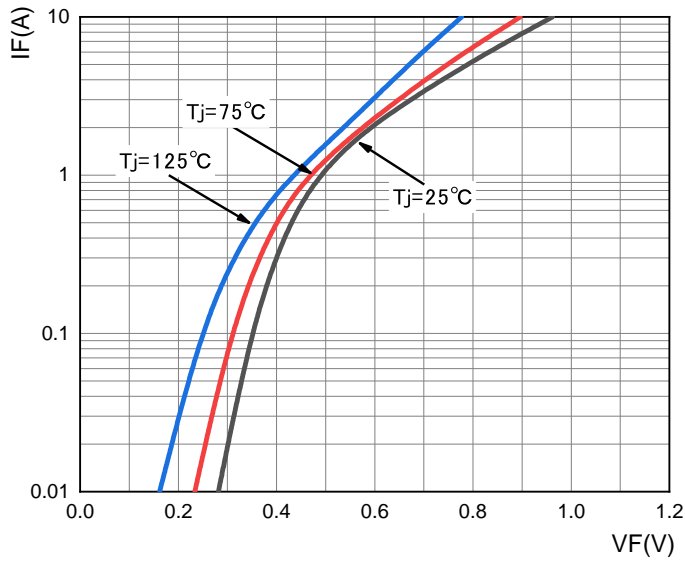
SS22 THRU SS220

Schottky Rectifier Diodes

Typical Characteristics

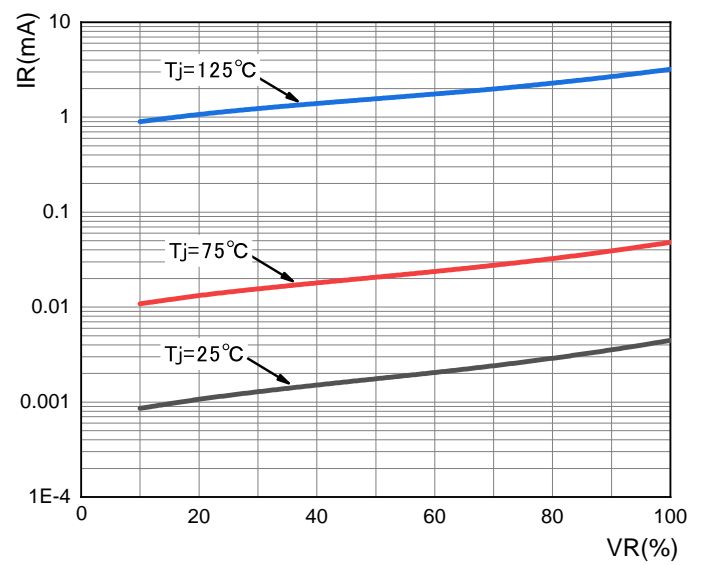
SS25-SS26

FIG.5: TYPICAL FORWARD CHARACTERISTICS



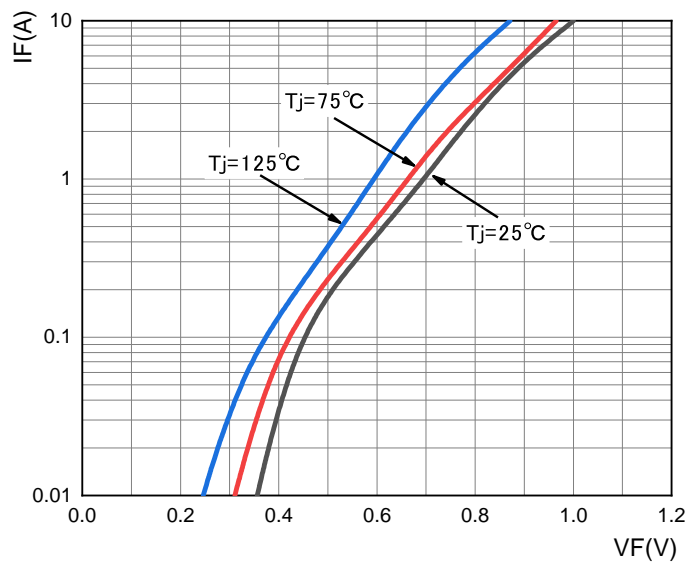
SS25-SS26

FIG.6: TYPICAL REVERSE CHARACTERISTICS



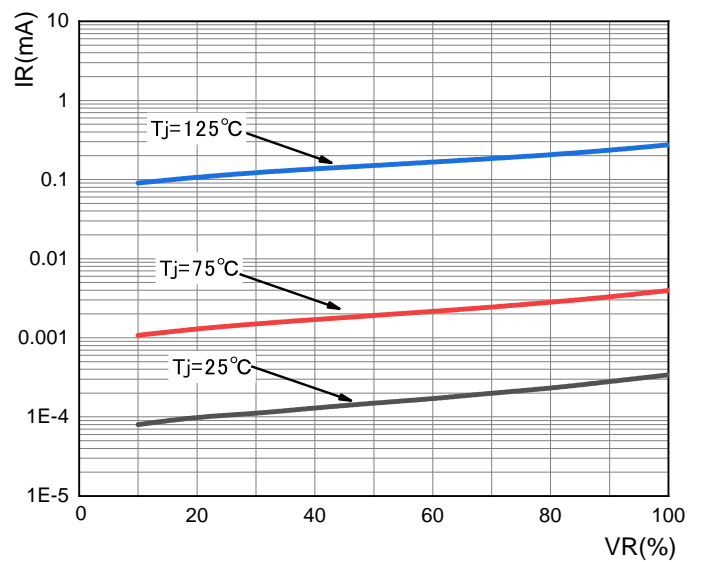
SS28-SS210

FIG.7: TYPICAL FORWARD CHARACTERISTICS



SS28-SS210

FIG.8: TYPICAL REVERSE CHARACTERISTICS





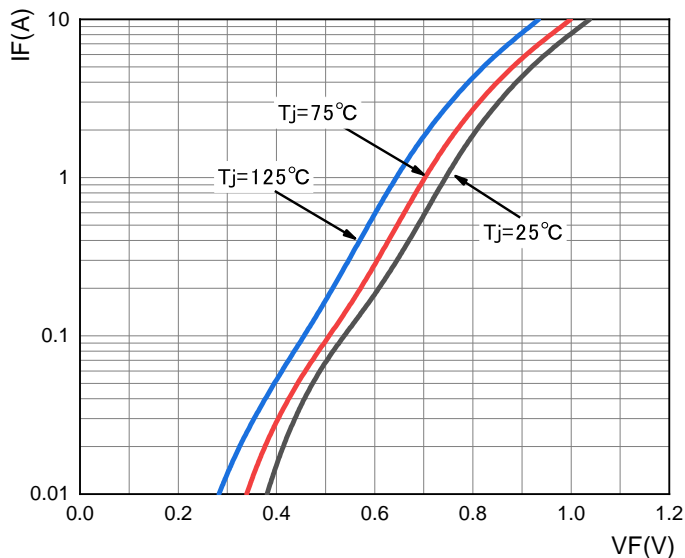
SS22 THRU SS220

Schottky Rectifier Diodes

Typical Characteristics

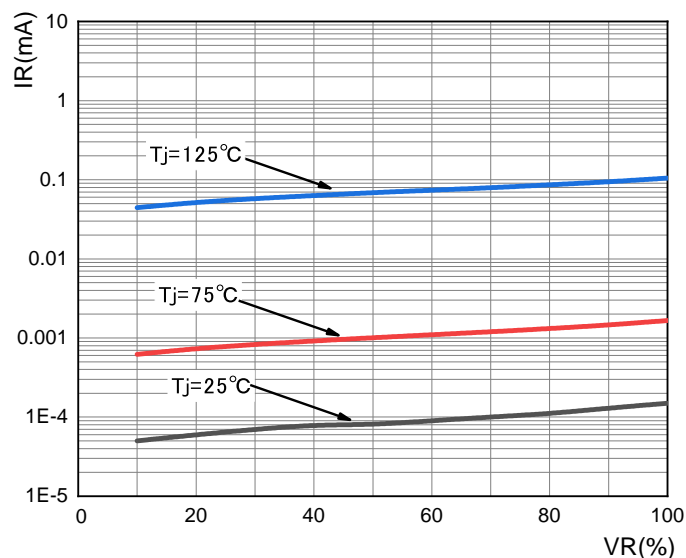
SS215

FIG.9: TYPICAL FORWARD CHARACTERISTICS



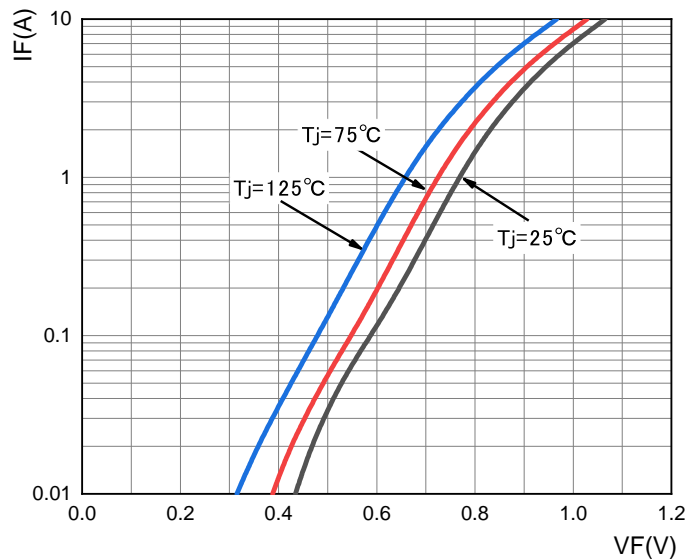
SS215

FIG.10: TYPICAL REVERSE CHARACTERISTICS



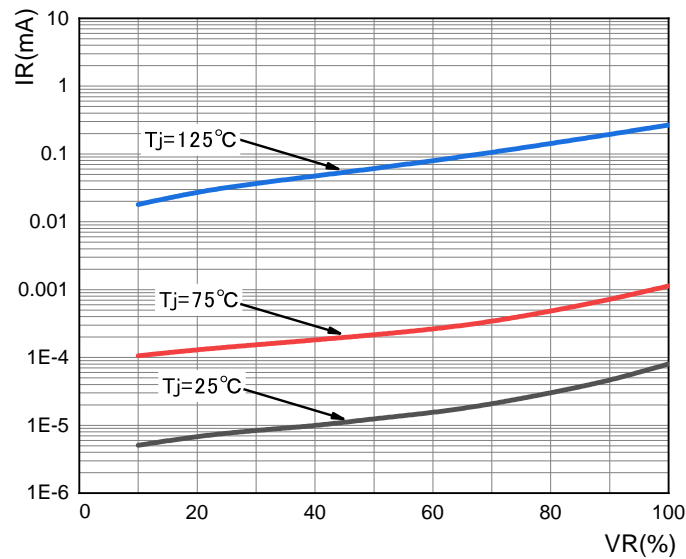
SS220

FIG.11: TYPICAL FORWARD CHARACTERISTICS

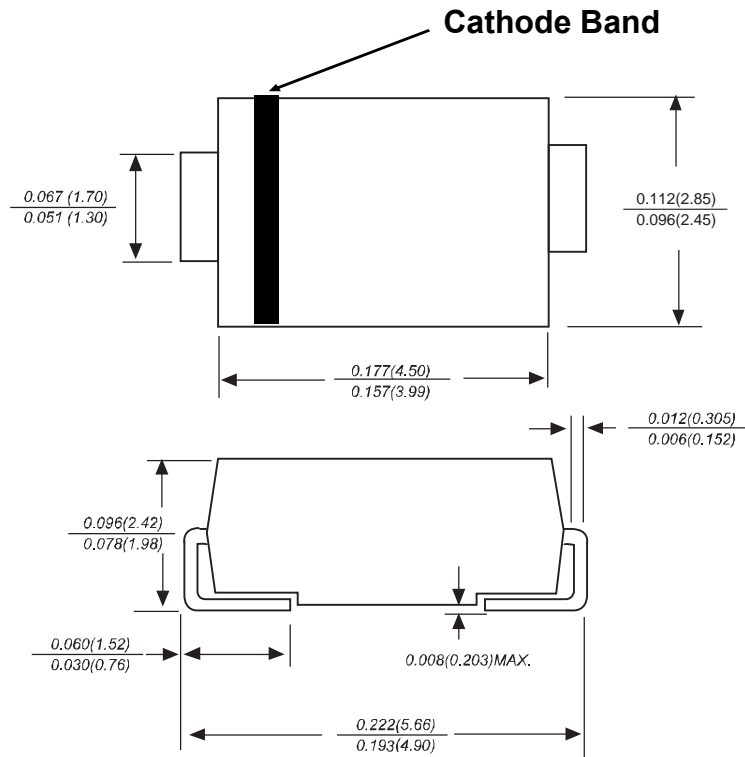


SS220

FIG.12: TYPICAL REVERSE CHARACTERISTICS

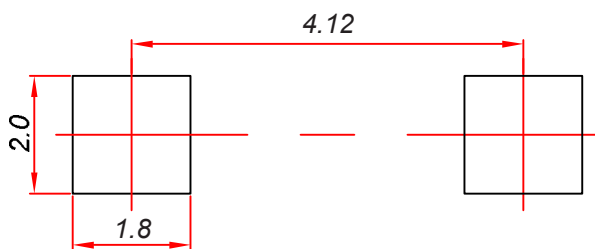


SMA Package Outline Dimensions



Dimensions in inches and (millimeters)

SMA Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

Reel Taping Specifications For Surface Mount Devices- SMA

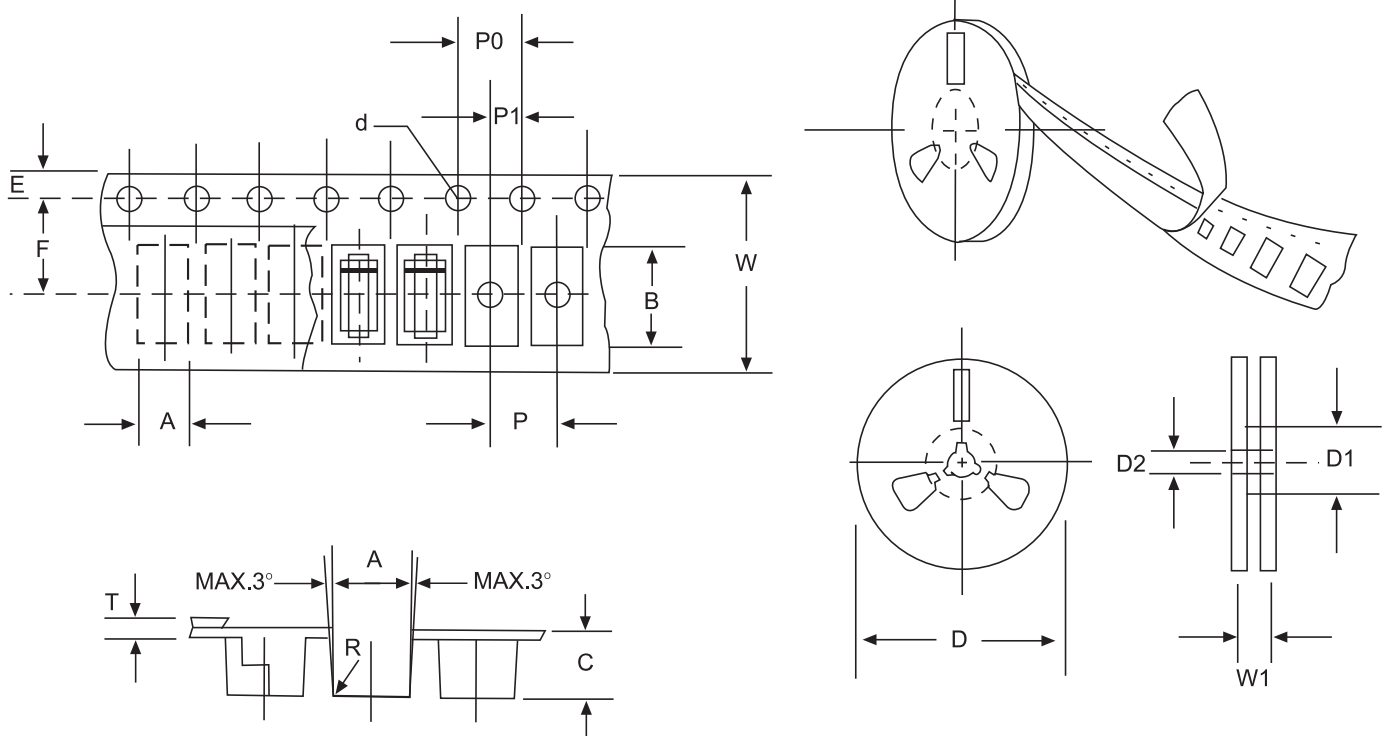


FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	SMAG mm(inch)
Carrier width	A	2.79±0.1(0.110±0.004)
Carrier length	B	5.33±0.1(0.210±0.004)
Carrier depth	C	2.36±0.1(0.093±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	279±2.0 (11± 0.079)
Reel inner diameter	D1	75 ±1.0 (2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Sprocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.5±0.05(0.217±0.002)
Punch hole pitch	P	4.0±0.1(0.157±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Totall tape thickness	T	0.28±0.02(0.011 ±0.0008)
Tape width	W	12.0±0.2(0.472±0.008)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.